Vishay General Semiconductor

Surface Mount Schottky Barrier Rectifier



SHA

DO-214AC (SMA)

MAJOR RATINGS AND CHARACTERISTICS

I_{F(AV)}

V_{RRM}

I_{FSM}

 V_{F}

T_i max.

1.0 A

20 V to 60 V

40 A

0.50 V, 0.70 V

125 °C, 150 °C

FEATURES

- · Low profile package
- · Ideal for automated placement
- · Guardring for overvoltage protection
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- Meets MSL level 1, per J-STD-020C
- Solder Dip 260 °C, 40 seconds

TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

MECHANICAL DATA

Case: DO-214AC (SMA)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D E3 suffix for commercial grade, HE3 suffix for high reliability grade (AEC Q101 qualified)

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	SS12	SS13	SS14	SS15	SS16	UNIT	
Device marking code		S2	S3	S4	S5	S6	V	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	V	
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	V	
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	V	
Maximum average forward rectified current at T_L (see Fig. 1)	I _{F(AV)}	1.0					A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	40					A	
Voltage rate of change (rated V _R)	dv/dt	10000					V/µs	
Operating junction temperature range	Τ _J	- 65 to + 125 - 65 to + 150			°C			
Storage temperature range	T _{STG}	- 65 to + 150					°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)										
PARAMETER	TEST CONDITION	SYMBOL	SS12	SS13	SS14	SS15	SS16	UNIT		
Maximum instantaneous forward voltage	at 1.0 A ⁽¹⁾	V _F	0.50			0.75		V		
Maximum DC reverse current at rated	T _A = 25 °C	1	0.2					mA		
DC blocking voltage ⁽¹⁾	T _A = 100 °C	^I R		6.0		5.	.0			

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	SS12	SS13	SS14	SS15	SS16	UNIT			
Typical thermal resistance ⁽¹⁾	$R_{ extsf{ heta}JA}\ R_{ extsf{ heta}JL}$		°C/W							

Note:

(1) P.C.B. mounted with 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)



Figure 1. Forward Current Derating Curve



Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



Figure 3. Typical Instantaneous Forward Characteristics



Figure 4. Typical Reverse Characteristics



SS12 thru SS16

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Figure 5. Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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